

Tianshu Li

List of Publications by Year in descending order

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42

papers

11,016

citations

236925

25

h-index

276875

41

g-index

43

all docs

43

docs citations

43

times ranked

15363

citing authors

#	ARTICLE	IF	CITATIONS
1	Homogeneous ice nucleation rate at negative pressures: The role of the density anomaly. <i>Chemical Physics Letters</i> , 2022, 789, 139289.	2.6	3
2	Phase-Controllable Synthesis of Ultrathin Molybdenum Nitride Crystals Via Atomic Substitution of MoS ₂ . <i>Chemistry of Materials</i> , 2022, 34, 351-357.	6.7	12
3	Flexible and high-performance electrochromic devices enabled by self-assembled 2D TiO ₂ /MXene heterostructures. <i>Nature Communications</i> , 2021, 12, 1587.	12.8	143
4	Spin-induced linear polarization of photoluminescence in antiferromagnetic van der Waals crystals. <i>Nature Materials</i> , 2021, 20, 964-970.	27.5	59
5	Mechanical Instability of Methane Hydrate–Mineral Interface Systems. <i>ACS Applied Materials & Interfaces</i> , 2021, 13, 46043-46054.	8.0	12
6	Short-range order in SiSn alloy enriched by second-nearest-neighbor repulsion. <i>Physical Review Materials</i> , 2021, 5, .	2.4	3
7	Mechanical Response of Nanocrystalline Ice-Contained Methane Hydrates: Key Role of Water Ice. <i>ACS Applied Materials & Interfaces</i> , 2020, 12, 14016-14028.	8.0	23
8	Anisotropic Phonon Response of Few-layer PdSe ₂ under Uniaxial Strain. <i>Advanced Functional Materials</i> , 2020, 30, 2003215.	14.9	26
9	Realization of 2D crystalline metal nitrides via selective atomic substitution. <i>Science Advances</i> , 2020, 6, eaax8784.	10.3	66
10	Short-Range Order in GeSn Alloy. <i>ACS Applied Materials & Interfaces</i> , 2020, 12, 57245-57253.	8.0	20
11	Partial Local Atomic Ordering in Ge-Sn Alloy. , 2019, .	0	
12	Anomalous Stability of Two-Dimensional Ice Confined in Hydrophobic Nanopores. <i>ACS Nano</i> , 2019, 13, 4712-4719.	14.6	19
13	Probing the Domain Architecture in 2D Mo ₂ C via Polarized Raman Spectroscopy. <i>Advanced Materials</i> , 2019, 31, e1807160.	21.0	58
14	Effect of hydrophilic silica nanoparticles on hydrate formation: Insight from the experimental study. <i>Journal of Energy Chemistry</i> , 2019, 30, 90-100.	12.9	61
15	Formation of inclusion type silicon phases induced by inert gases. <i>Communications Chemistry</i> , 2018, 1, .	4.5	6
16	Mechanical properties of bi- and poly-crystalline ice. <i>AIP Advances</i> , 2018, 8, .	1.3	14
17	Semiconducting cubic titanium nitride in the $\text{Th}_{3}\text{Mn}_{24}$ structure. <i>Physical Review Materials</i> , 2018, 2, .	2.4	24
18	Enhanced heterogeneous ice nucleation by special surface geometry. <i>Nature Communications</i> , 2017, 8, 15372.	12.8	120

#	ARTICLE	IF	CITATIONS
19	Free energy landscape and molecular pathways of gas hydrate nucleation. <i>Journal of Chemical Physics</i> , 2016, 145, 211909.	3.0	62
20	Microscopic Mechanism and Kinetics of Ice Formation at Complex Interfaces: Zooming in on Kaolinite. <i>Journal of Physical Chemistry Letters</i> , 2016, 7, 2350-2355.	4.6	77
21	Heterogeneous Ice Nucleation Controlled by the Coupling of Surface Crystallinity and Surface Hydrophilicity. <i>Journal of Physical Chemistry C</i> , 2016, 120, 1507-1514.	3.1	104
22	Ice nucleation on carbon surface supports the classical theory for heterogeneous nucleation. <i>Physical Review E</i> , 2015, 91, 052402.	2.1	93
23	Interlayer Electronic Coupling in Arbitrarily Stacked MoS ₂ Bilayers Controlled by Interlayer S-S Interaction. <i>Journal of Physical Chemistry C</i> , 2015, 119, 1247-1252.	3.1	25
24	Pressure-Modulated Conductivity, Carrier Density, and Mobility of Multilayered Tungsten Disulfide. <i>ACS Nano</i> , 2015, 9, 9117-9123.	14.6	120
25	Reply to "Comment on "Ideal strength and phonon instability in single-layer MoS ₂ " by M. H. Whang et al." <i>Physical Review B</i> , 2014, 90, .	3.2	12
26	Probing Methane Hydrate Nucleation through the Forward Flux Sampling Method. <i>Journal of Physical Chemistry B</i> , 2014, 118, 13324-13332.	2.6	83
27	Ice nucleation at the nanoscale probes no man's land of water. <i>Nature Communications</i> , 2013, 4, 1887.	12.8	112
28	Band offsets and dielectric properties of the amorphous Si ₃ N ₄ /Si(100) interface: A first-principles study. <i>Applied Physics Letters</i> , 2013, 102, .	3.3	23
29	Ideal strength and phonon instability in single-layer MoS ₂ . <i>Physical Review B</i> , 2012, 85, .	3.2	337
30	Tailored Nanoheterojunctions for Optimized Light Emission. <i>Physical Review Letters</i> , 2011, 107, 206805.	7.8	22
31	Homogeneous ice nucleation from supercooled water. <i>Physical Chemistry Chemical Physics</i> , 2011, 13, 19807.	2.8	226
32	Microscopic modeling of the dielectric properties of silicon nitride. <i>Physical Review B</i> , 2011, 84, .	3.2	14
33	First-principles investigations of the dielectric properties of crystalline and amorphous Si ₃ N ₄ thin films. <i>Applied Physics Letters</i> , 2010, 96, 062902.	3.3	25
34	Spreading of dislocation cores in elastically anisotropic body-centered-cubic materials: The case of gum metal. <i>Physical Review B</i> , 2010, 82, .	3.2	46
35	Emerging Photoluminescence in Monolayer MoS ₂ . <i>Nano Letters</i> , 2010, 10, 1271-1275.	9.1	7,897
36	Nucleation of tetrahedral solids: A molecular dynamics study of supercooled liquid silicon. <i>Journal of Chemical Physics</i> , 2009, 131, 224519.	3.0	34

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37	Surface-induced crystallization in supercooled tetrahedral liquids. <i>Nature Materials</i> , 2009, 8, 726-730.	27.5	84	
38	â€œidealâ€ Engineering Alloys. <i>Physical Review Letters</i> , 2007, 98, 105503.	7.8	181	
39	Electronic Properties of MoS ₂ Nanoparticles. <i>Journal of Physical Chemistry C</i> , 2007, 111, 16192-16196.	3.1	634	
40	Ab initio study of the ideal shear strength and elastic deformation behaviors of B2FeAl and NiAl. <i>Physical Review B</i> , 2006, 73, .	3.2	20	
41	Ideal tensile strength of B2 transition-metal aluminides. <i>Physical Review B</i> , 2004, 70, .	3.2	52	
42	Microstructure and nanoindentation hardness of Ti/TiN multilayered films. <i>Surface and Coatings Technology</i> , 2001, 137, 225-229.	4.8	64	